

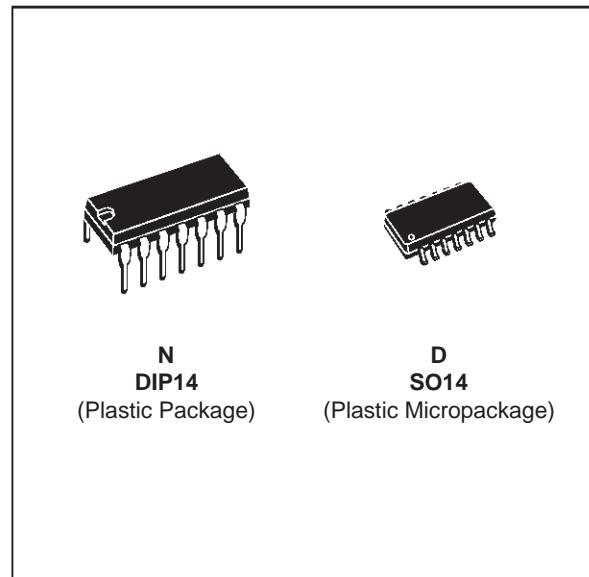


**SGS-THOMSON**  
MICROELECTRONICS

**MC33174 - MC35174**

**LOW POWER  
QUAD BIPOLAR OPERATIONAL AMPLIFIERS**

- GOOD CONSUMPTION/SPEED RATIO : ONLY 200 $\mu$ A/Amp FOR 2.1MHz, 2V/ $\mu$ s
- SINGLE (OR DUAL) SUPPLY OPERATION FROM +4V TO +44V ( $\pm$ 2V TO  $\pm$ 22V)
- WIDE INPUT COMMON MODE VOLTAGE RANGE INCLUDING V<sub>CC</sub>
- LOW LEVEL OUTPUT VOLTAGE CLOSE TO V<sub>CC</sub>: 100mV TYPICAL
- PIN TO PIN COMPATIBLE WITH STANDARD QUAD OP AMPS
- ESD PROTECTION



### DESCRIPTION

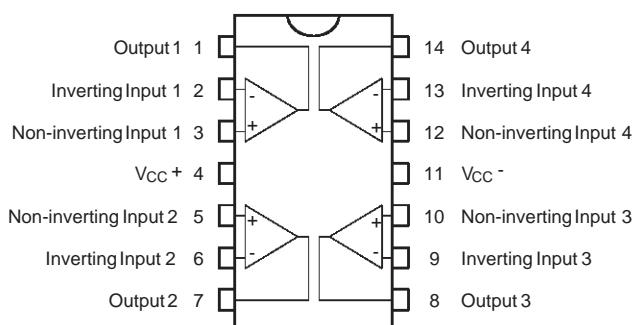
The MC33174 series are quad bipolar operational amplifiers offering both low consumption (200 $\mu$ A/Amp) and good speed (2.1MHz, 2V/ $\mu$ s).

Moreover the Input Common Mode Range extends down to the lower supply rail, allowing single supply operation from +4V to +44V.

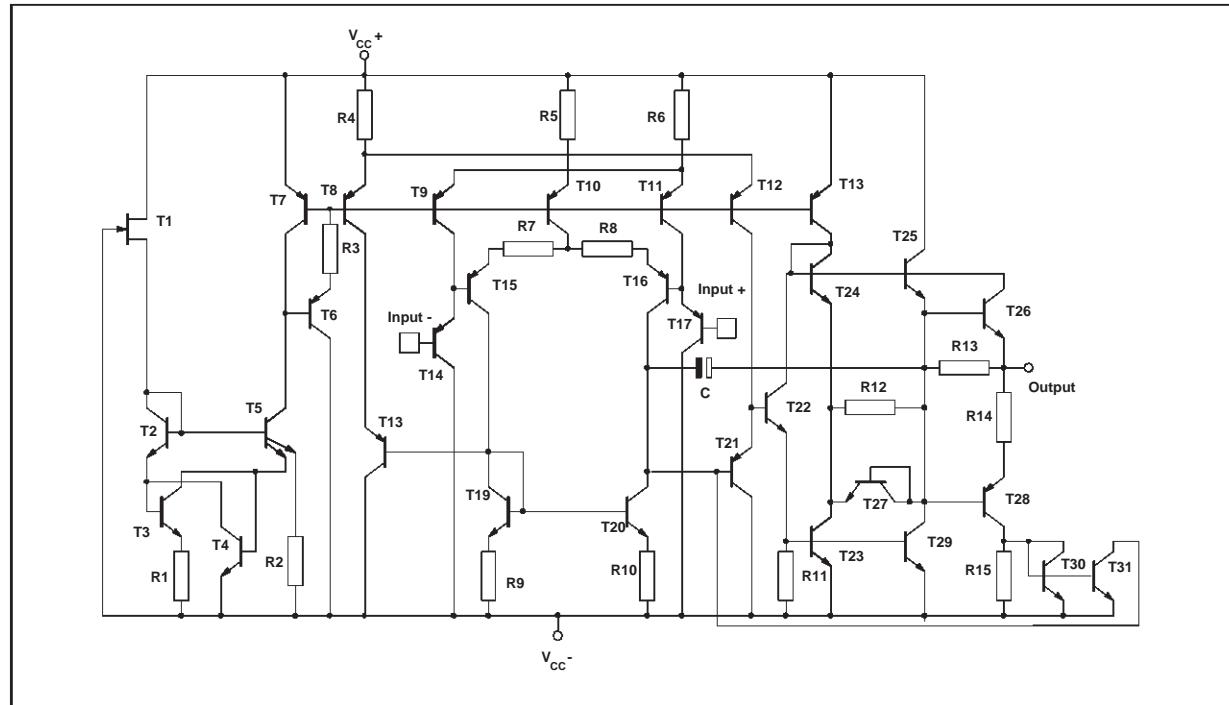
### ORDER CODES

Part Number	Temperature Range	Package	
		N	D
MC33174	-40°C, +105°C	•	•
MC35174	-55°C, +125°C	•	•
<b>Example:</b> MC33174N			

### PIN CONNECTIONS (top view)



**SCHEMATIC DIAGRAM** (for 1/4 MC33174)



**ABSOLUTE MAXIMUM RATINGS**

Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage	±22	V
V <sub>id</sub>	Differential Input Voltage	(Note 1)	V
V <sub>i</sub>	Input Voltage	(Note 1)	V
	Output Short Circuit Duration	Indefinite	s
T <sub>oper</sub>	Operating Temperature Range	MC33174 MC35174	-40 to 105 -55 to 125
T <sub>j</sub>	Junction Temperature	150	°C
T <sub>stg</sub>	Storage Temperature	-65 to 150	°C

Note 1: Either or both input voltages must not exceed the magnitude of V<sub>cc</sub>.

**OPERATING CONDITIONS**

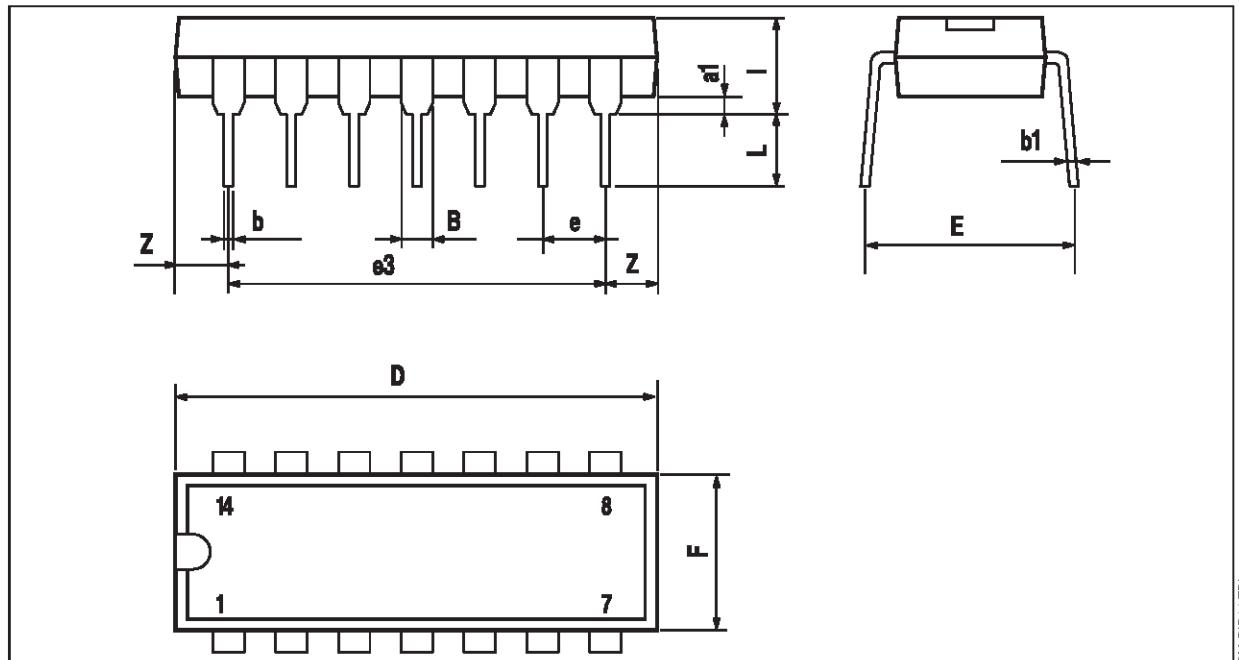
Symbol	Parameter	Value	Unit
V <sub>CC</sub>	Supply Voltage Range	±2 to ±22	V

**ELECTRICAL CHARACTERISTICS**V<sub>CC</sub><sup>+</sup> = +15V, V<sub>CC</sub><sup>-</sup> = -15V, R<sub>L</sub> connected to Ground, T<sub>amb</sub> = 25°C (unless otherwise specified)

Symbol	Parameter	Min.	Typ.	Max.	Unit
V <sub>io</sub>	Input Offset Voltage V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, V <sub>ic</sub> = 0V V <sub>CC</sub> <sup>+</sup> = 5V, V <sub>CC</sub> <sup>-</sup> = 0V, V <sub>ic</sub> = 0V, V <sub>o</sub> = 1.4V V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, V <sub>ic</sub> = 0V, T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>		1 1	4.5 5 6.5	mV
DV <sub>io</sub>	Input Offset Voltage Drift		10		µV/°C
I <sub>io</sub>	Input Offset Current (V <sub>ic</sub> = 0V) T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>		5 40	20	nA
I <sub>ib</sub>	Input Bias Current (V <sub>ic</sub> = 0V) T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>		20	100 200	nA
A <sub>vd</sub>	Large Signal Voltage Gain (R <sub>L</sub> = 10kΩ, V <sub>O</sub> = ±10V) T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>	50 25	100		V/mV
V <sub>OH</sub>	High Level Output Voltage V <sub>CC</sub> <sup>+</sup> = 5V, V <sub>CC</sub> <sup>-</sup> = 0V, R <sub>L</sub> = 10kΩ V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, R <sub>L</sub> = 10kΩ V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, R <sub>L</sub> = 10kΩ, T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>	3.5 13.6 13.3	4.2 14.2		V
V <sub>OL</sub>	Low Level Output Voltage V <sub>CC</sub> <sup>+</sup> = 5V, V <sub>CC</sub> <sup>-</sup> = 0V, R <sub>L</sub> = 10kΩ V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, R <sub>L</sub> = 10kΩ V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, R <sub>L</sub> = 10kΩ, T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>		0.1 -14	0.15 -13.6 -13.3	V
I <sub>sc</sub>	Output Short Circuit Current (V <sub>id</sub> = ±1V, V <sub>O</sub> = 0V) Source Sink	3 15	6 27		mA
V <sub>icm</sub>	Input Common Mode Voltage Range T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>	V <sub>CC</sub> <sup>-</sup> to (V <sub>CC</sub> <sup>+</sup> - 1.8) V <sub>CC</sub> <sup>-</sup> to (V <sub>CC</sub> <sup>+</sup> - 2.2)			V
CMR	Common Mode Rejection Ratio (V <sub>i</sub> = V <sub>icm min.</sub> )	80	100		dB
SVR	Supply Voltage Rejection Ratio (V <sub>CC</sub> = ±5 to ±15V)	80	100		dB
I <sub>cc</sub>	Supply Current (per amplifier) V <sub>CC</sub> <sup>+</sup> = 5V, V <sub>CC</sub> <sup>-</sup> = 0V, no load V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, no load V <sub>CC</sub> <sup>+</sup> = +15V, V <sub>CC</sub> <sup>-</sup> = -15V, no load, T <sub>min.</sub> ≤ T <sub>amb</sub> ≤ T <sub>max.</sub>		200 220	250 250 300	µA
SR	Slew Rate (V <sub>i</sub> = ±10V, R <sub>L</sub> = 10kΩ, C <sub>L</sub> = 100pF)	1.6	2		V/µs
GBP	Gain Bandwidth Product (R <sub>L</sub> = 10kΩ, C <sub>L</sub> = 100pF, f = 100kHz)	1.4	2.1		MHz
Øm	Phase Margin (R <sub>L</sub> = 10kΩ, C <sub>L</sub> = 100pF)		45		Degrees
e <sub>n</sub>	Equivalent Input Noise Voltage (f = 1kHz)		29		$\frac{nV}{\sqrt{Hz}}$
THD	Total Harmonic Distortion		0.05		%
V <sub>O1</sub> /V <sub>O2</sub>	Channel Separation		120		dB

# MC33174 - 35174

## PACKAGE MECHANICAL DATA 14 PINS - PLASTIC DIP



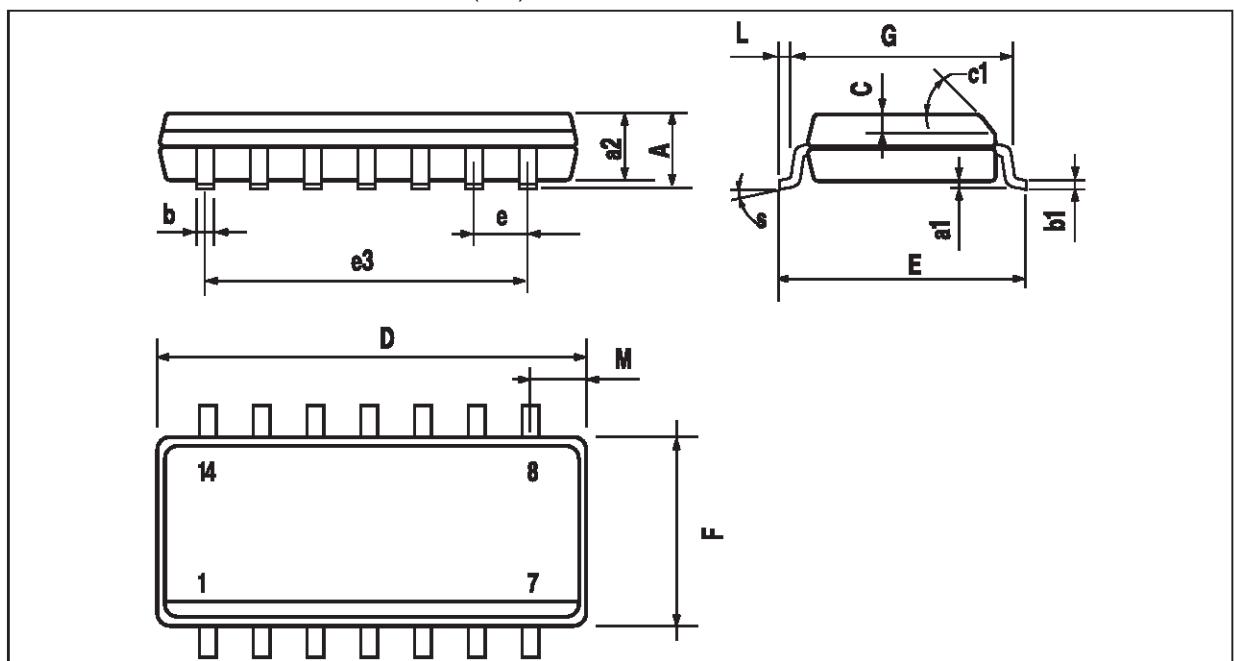
PM-DIP14.TBL

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
a1	0.51			0.020		
B	1.39		1.65	0.055		0.065
b		0.5			0.020	
b1		0.25			0.010	
D			20			0.787
E		8.5			0.335	
e		2.54			0.100	
e3		15.24			0.600	
F			7.1			0.280
i			5.1			0.201
L		3.3			0.130	
Z	1.27		2.54	0.050		0.100

DIP14.TBL

## PACKAGE MECHANICAL DATA

14 PINS - PLASTIC MICROPACKAGE (SO)



PM-DIP14.EPS

Dimensions	Millimeters			Inches		
	Min.	Typ.	Max.	Min.	Typ.	Max.
A			1.75			0.069
a1	0.1		0.2	0.004		0.008
a2			1.6			0.063
b	0.35		0.46	0.014		0.018
b1	0.19		0.25	0.007		0.010
C		0.5			0.020	
c1	45° (typ.)					
D	8.55		8.75	0.336		0.334
E	5.8		6.2	0.228		0.244
e		1.27			0.050	
e3		7.62			0.300	
F	3.8		4.0	0.150		0.157
G	4.6		5.3	0.181		0.208
L	0.5		1.27	0.020		0.050
M			0.68			0.027
S	8° (max.)					

SO14.TBL

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